Advanced Micro Devices

PAL20R8 Family

24-Pin TTL Programmable Array Logic

DISTINCTIVE CHARACTERISTICS

- As fast as 5 ns maximum propagation delay
- Popular 24-pin architectures: 20L8, 20R8, 20R6, 20R4
- Programmable replacement for high-speed TTL logic
- Power-up reset for initialization
- Extensive third-party software and programmer support through FusionPLD partners
- 24-pin SKINNYDIP and 28-pin PLCC packages save space

GENERAL DESCRIPTION

The PAL20R8 Family (PAL20L8, PAL20R8, PAL20R6, PAL20R4) includes the PAL20R8-5 Series which is ideal for high-performance applications. The PAL20R8 Family is provided in the standard 24-pin DIP and 28-pin PLCC pinouts.

The family utilizes Advanced Micro Devices' advanced trench-isolated bipolar process and fuse-link technology. The devices provide user programmable logic for replacing conventional SSI/LSI gates and flip-flops at a reduced chip cost.

The family allows the systems engineer to implement the design on-chip, by opening fuse links to configure AND and OR gates within the device, according to the desired logic function. Complex interconnections between gates, which previously required time-consuming layout, are lifted from the PC board and placed on silicon, where they can be easily modified during prototyping or production.

The PAL device implements the familiar Boolean logic transfer function, the sum of products. The PAL device is a programmable AND array driving a fixed OR array. The AND array is programmed to create custom product terms, while the OR array sums selected terms at the outputs.

In addition, the PAL device provides the following options:

- Variable input/output pin ratio
- Programmable three-state outputs
- Registers with feedback

Product terms with all connections opened assume the logical HIGH state; product terms connected to both true and complement of any single input assume the logical LOW state. Registers consist of D-type flip-flops that are loaded on the LOW-to-HIGH transition of the clock. Unused input pins should be tied to Vcc or GND.

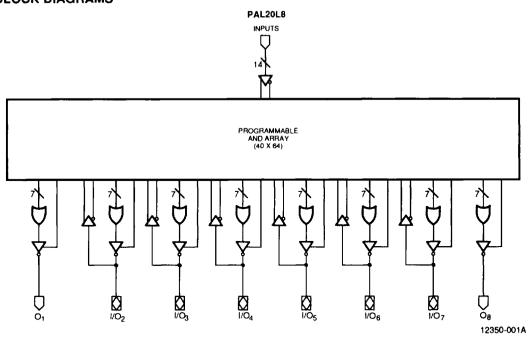
AMD's FusionPLD program allows PAL20R8 Family designs to be implemented using a wide variety of popular industry-standard design tools. By working closely with the FusionPLD partners, AMD certifies that the tools provide accurate, quality support. By ensuring that third-parly tools are available, costs are lowered because a designer does not have to buy a complete set of new tools for each device. The FusionPLD program also greatly reduces design time since a designer can use a tool that is already installed and familiar. Please refer to the PLD Software Reference Guide for certified development systems and the Programmer Reference Guide for approved programmers.

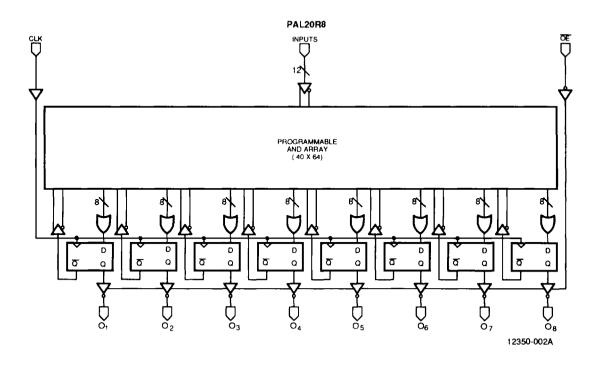
PRODUCT SELECTOR GUIDE

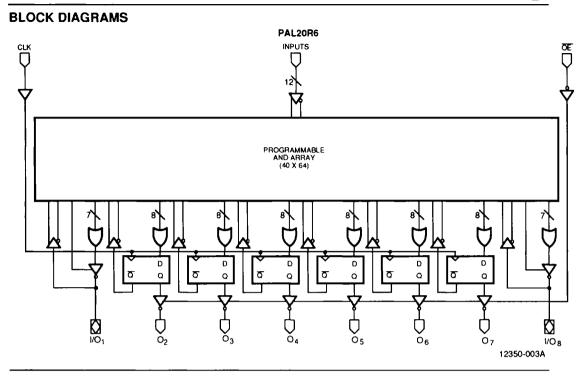
Device	Dedicated Inputs	Outputs	Product Terms/ Output	Feedback	Enable
PAL20L8	14	6 comb. 2 comb.	7 7	I/O -	prog. prog.
PAL20R8	12	8 reg.	8	reg.	pin
PAL20R6	12	6 reg. 2 comb.	8 7	reg. I/O	pin prog.
PAL20R4	12	4 reg. 4 comb.	8 7	reg. I/O	pin prog.

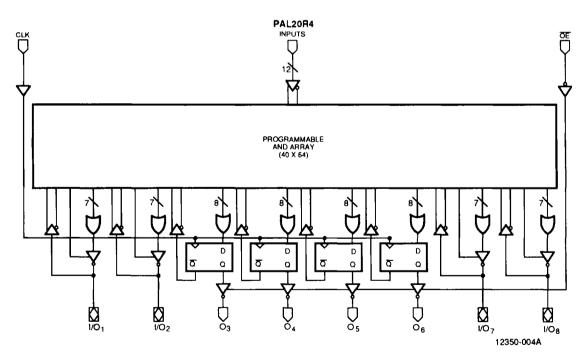
Publication# 16490 Rev. A Amendment/0-Issue Date: January 1992

BLOCK DIAGRAMS



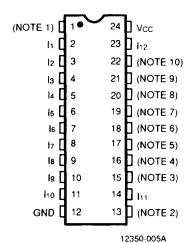






CONNECTION DIAGRAMS Top View

SKINNYDIP/FLATPACK



Note:

Pin 1 is marked for orientation.

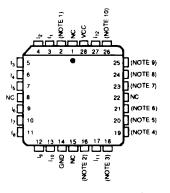
Note	20L8	20R8	20R6	20R4
1_	lo	CLK	CLK	CLK
2	l ₁₃	ŌĒ	ŌĒ	ŌĒ
3	O ₁	O ₁	1/01	I/O ₁
4	I/O ₂	O ₂	O ₂	I/O ₂
5	I/O ₃	O ₃	O ₃	О3
6	1/04	O ₄	O ₄	O ₄
7	I/O ₅	O ₅	O ₅	O ₅
8	I/O ₆	O ₆	O ₆	O ₆
9	1/07	O ₇	O ₇	I/O ₇
10	O ₈	O ₈	I/O ₈	I/O ₈

PIN DESIGNATIONS

CLK	Clock
GND	Ground
1	Input
1/0	Input/Output
NC	No Connect
0	Output
ŌĒ	Output Enable
Vcc	Supply Voltage

PLCC/LCC

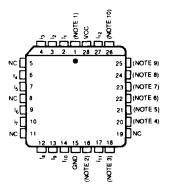
JEDEC Applies to -5, -7(-12/10 mil), -10(-15 mil), B-2 Series Only



12350-006A

PLCC

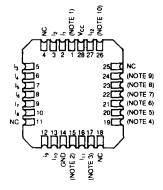
Applies to B and A Series Only



16490A-001A

LCC

Applies to B and A Series Only

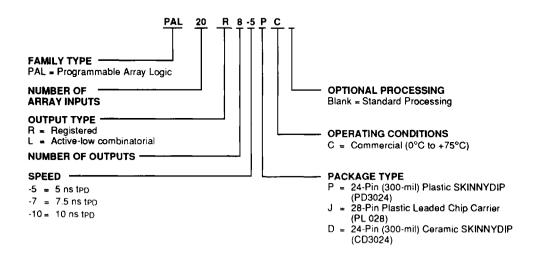


16490A-002A

ORDERING INFORMATION

Commercial Products

AMD programmable logic products for commercial applications are available with several ordering options. The order number (Valid Combination) is formed by a combination of:



Valid Combinations				
PAL20L8-5				
PAL20R8-5	DC 10			
PAL20R6-5	PC, JC			
PAL20R4-5				
PAL20L8-7				
PAL20L8-10				
PAL20R8-7				
PAL20R8-10	PC, JC, DC			
PAL20R6-7	FC, 3C, DC			
PAL20R6-10				
PAL20R4-7				
PAL20R4-10				

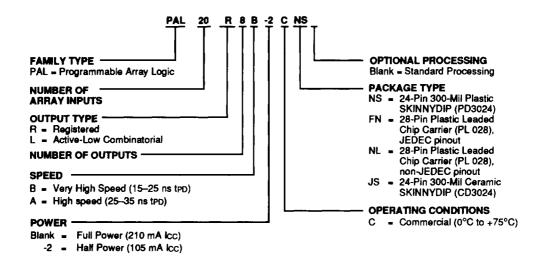
Valid Combinations

The Valid Combinations table lists configurations planned to be supported in volume for this device. Consult the local AMD sales office to confirm availability of specific valid combinations, and to check on newly released combinations.

Note: Marked with AMD logo.

ORDERING INFORMATION Commercial Products (MMI Marking Only)

AMD programmable logic products for commercial applications are available with several ordering options. The order number (Valid Combination) is formed by a combination of:



Valid Combinations				
PAL20L8	B-2	CNS, CFN, CJS		
PAL20R8				
PAL20R6	B, A	CNS, CNL, CJS		
PAL20R4	ŀ	1		

Valid Combinations

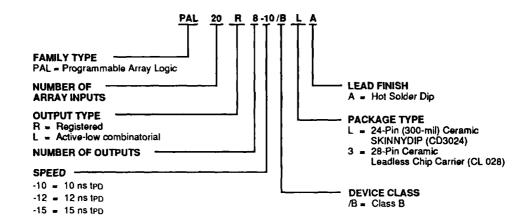
The Valid Combinations table lists configurations planned to be supported in volume for this device. Consult the local AMD sales office to confirm availability of specific valid combinations, and to check on newly released combinations.

Note: Marked with MMI logo.



ORDERING INFORMATION APL Products

AMD programmable logic products for Aerospace and Defense applications are available with several ordering options. APL (Approved Products List) products are fully compliant with MIL-STD-883 requirements. The order number (Valid Combination) is formed by a combination of:



Valid Combinations					
PAL20L8					
PAL20R8	10 10 15	/DIA /DOA			
PAL20R6	-10, -12, -15	/BLA, /B3A			
PAL20R4					

Valid Combinations

The Valid Combinations table lists configurations planned to be supported in volume for this device. Consult the local AMD sales office to confirm availability of specific valid combinations, to check on newly released combinations, and to obtain additional data on AMD's standard military grade products.

Note: Marked with AMD logo.

Group A Tests

Group A Tests consist of Subgroups: 1, 2, 3, 7, 8, 9, 10, 11.

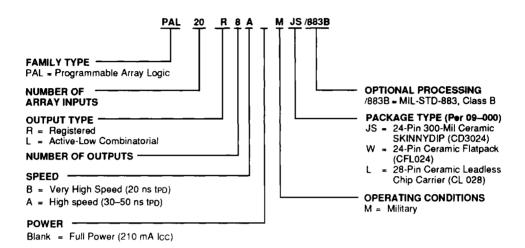
Military Burn-In

Military burn-in is in accordance with the current revision of MIL-STD-883, Test Methods 1015, Conditions A through E. Test conditions are selected at AMD's option.

ORDERING INFORMATION

APL Products (MMI Marking Only)

AMD programmable logic products for Aerospace and Defense applications are available with several ordering options. APL (Approved Products List) products are fully compliant with MIL-STD-883 requirements. The order number (Valid Combination) is formed by a combination of:



Valid Combinations					
PAL20L8					
PAL20R8	D 4	MJS/883B,			
PAL20R6	В, А	MW/883B, ML/883B			
PAL20R4					

Valid Combinations

The Valid Combinations table lists configurations planned to be supported in volume for this device. Consult the local AMD sales office to confirm availability of specific valid combinations, and to check on newly released combinations.

Note: Marked with MMI logo.

Group A Tests

Group A Tests consist of Subgroups: 1, 2, 3, 7, 8, 9, 10, 11.

Military Burn-In

Military burn-in is in accordance with the current revision of MIL-STD-883, Test Methods 1015, Conditions A through E. Test conditions are selected at AMD's option.

FUNCTIONAL DESCRIPTION Standard 24-Pin PAL Family

The standard 24-pin PAL family is comprised of four different devices, including both registered and combinatorial devices. All parts are produced with a fuse link at each input to the AND gate array, and connections may be selectively removed by applying appropriate voltages to the circuit. Using any of a number of development packages, these products can be rapidly programmed to any customized pattern. Extra test words are pre-programmed during manufacturing to ensure extremely high field programming yields, and provide extra test paths to achieve excellent parametric correlation.

Variable Input/Output Pin Ratio

The registered devices have twelve dedicated input lines, and each combinatorial output is an I/O pin. The PAL20L8 has fourteen dedicated input lines, and only six of the eight combinatorial outputs are I/O pins. Buffers for device inputs have complementary outputs to provide user-programmable input signal polarity. Unused input pins should be tied to Vcc or GND.

Programmable Three-State Outputs

Each output has a three-state output buffer with three-state control. On combinatorial outputs, a product term controls the buffer, allowing enable and disable to be a function of any product of device inputs or output feedback. The combinatorial output provides a bidirectional I/O pin, and may be configured as a dedicated input if the buffer is always disabled. On registered outputs, an input pin controls the enabling of the three-state outputs.

Registers with Feedback

Registered outputs are provided for data storage and synchronization. Registers are composed of D-type flip-flops that are loaded on the LOW-to-HIGH transition of the clock input.

Power-Up Reset

All flip-flops power-up to a logic LOW for predictable system initialization. Outputs of the PAL20R8 Family will be HIGH due to the active-low outputs. The Vcc rise must be monotonic and the reset delay time is 1000 ns maximum

Register Preload

The register on the PAL20R8 Family can be preloaded from the output pins to facilitate functional testing of complex state machine designs. This feature allows direct loading of arbitrary states, making it unnecessary to cycle through long test vector sequences to reach a desired state. In addition, transitions from illegal states can be verified by loading illegal states and observing proper recovery.

Security Fuse

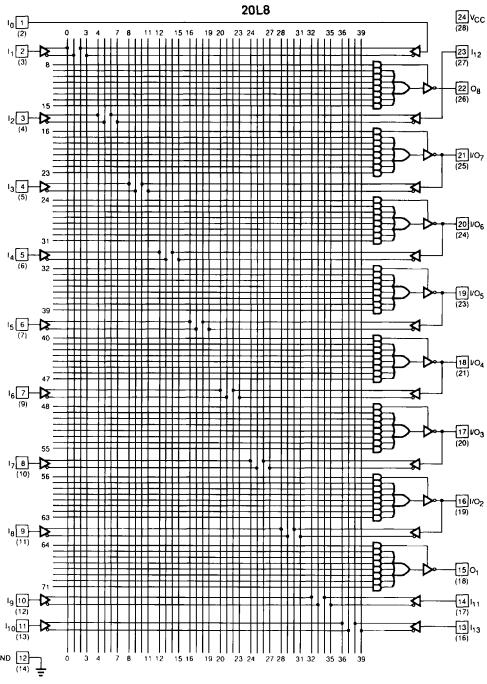
After programming and verification, a PAL20R8 Family design can be secured by programming the security fuse. Once programmed, this fuse defeats readback of the internal programmed pattern by a device programmer, securing proprietary designs from competitors. When the security fuse is programmed, the array will read as if every fuse is intact.

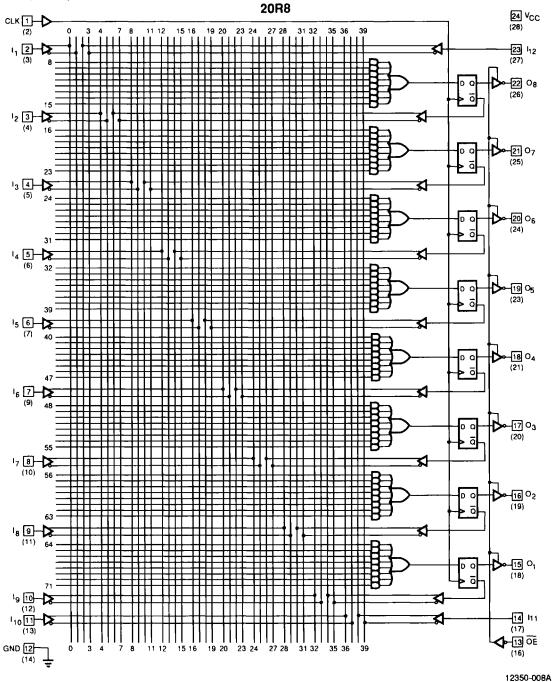
Quality and Testability

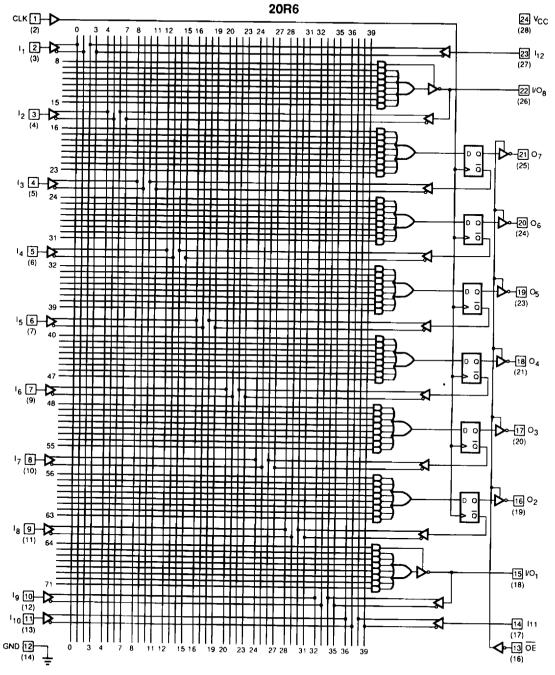
The PAL20R8 Family offers a very high level of built-in quality. Extra programmable fuses provide a means of verifying performance of all AC and DC parameters. In addition, this verifies complete programmability and functionality of the device to provide the highest programming yields and post-programming functional yields in the industry.

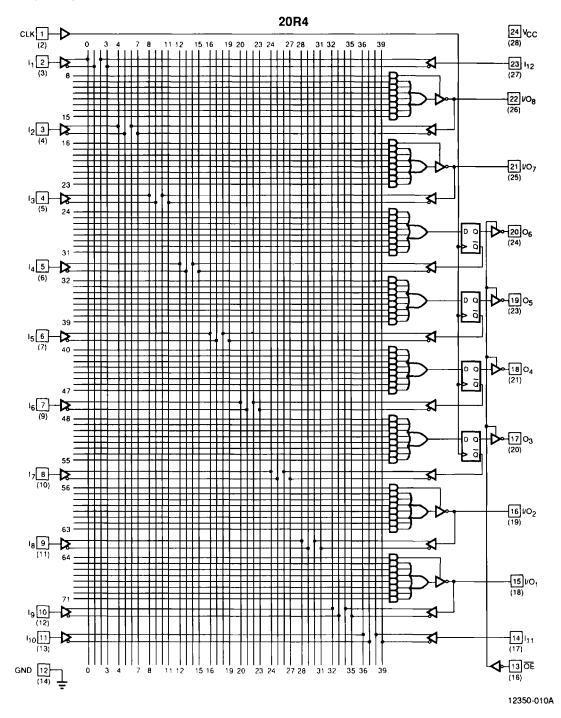
Technology

The high-speed PAL20R8 Family is fabricated with AMD's advanced trench-isolated bipolar process. This process reduces parasitic capacitances and minimum geometries to provide higher performance. The array connections are formed with proven TiW fuses.











Storage Temperature -65°C to +150°C

Ambient Temperature with

ity. Programming conditions may differ.

Power Applied -55°C to +125°C

Supply Voltage with

Respect to Ground -0.5 V to +7.0 V

DC Input Voltage -1.2 V to Vcc + 0.5 V

DC Output or I/O Pin Voltage -0.5 V to $V_{CC} + 0.5 \text{ V}$

Static Discharge Voltage 2001 V
Stresses above those listed under Absolute Maximum Rat-

ings may cause permanent device failure. Functionality at or above these limits is not implied. Exposure to Absolute Maximum Ratings for extended periods may affect device reliabilAmbient Temperature (T_A)
Operating in Free Air

0°C to 75°C

Supply Voltage (Vcc)

OPERATING RANGES

Commercial (C) Devices

with Respect to Ground

4.75 V to 5.25 V

Operating ranges define those limits between which the functionality of the device is guaranteed.

DC CHARACTERISTICS over COMMERCIAL operating ranges unless otherwise specified

Parameter Symbol	Parameter Description	Test Conditions	Min.	Max.	Unit
Vон	Output HIGH Voltage	IOH = -3.2 mA V _{IN} = V _{IH} or V _{IL} V _{CC} = Min.	2.4		V
Vol	Output LOW Voltage	IoL = 24 mA V _{IN} = V _{IH} or V _{IL} V _{CC} = Min.		0.5	V
ViH	Input HIGH Voltage	Guaranteed Input Logical HIGH Voltage for all Inputs (Note 1)	2.0		٧
VIL	Input LOW Voltage	Guaranteed Input Logical LOW Voltage for all Inputs (Note 1)		0.8	V
Vı	Input Clamp Voltage	In = -18 mA, Vcc = Min.		-1.2	
lin .	Input HIGH Current	Vin = 2.7 V, Vcc = Max. (Note 2)		25	μА
l _{IL}	Input LOW Current	Vin = 0.4 V, Vcc = Max. (Note 2)		-250	μA
lı	Maximum Input Current	V _{IN} = 5.5 V, V _{CC} = Max.		1	mA
lozн —-	Off-State Output Leakage Current HIGH	Vout = 2.7 V, Vcc = Max. Vin = Vih or Vil (Note 2)		100	μА
lozi.	Off-State Output Leakage Current LOW	Vout = 0.4 V, Vcc = Max. Vin = Vih or Vil (Note 2)		-100	μА
Isc	Output Short-Circuit Current	Vour = 0.5 V, Vcc = Max. (Note 3)	-30	-130	mA
lcc	Supply Current	Vin = 0 V, Outputs Open (lout = 0 mA) Vcc = Max.		210	mA

- 1. These are absolute values with respect to device ground and all overshoots due to system and/or tester noise are included.
- I/O pin leakage is the worst case of IIL and IOZL (or IIH and IOZH).
- Not more than one output should be tested at a time. Duration of the short-circuit should not exceed one second. Vout = 0.5 V
 has been chosen to avoid test problems caused by tester ground degradation.

CAPACITANCE (Note 1)

Parameter Symbol	Parameter Descrip	tion	Test Condition	s	Тур.	Unit
Cin	Input Capacitance	CLK, OE	V _{IN} = 2.0 V	Vcc = 5.0 V	8	
		l ₁ - l ₁₂		T _A = +25°C	5	pF
Соит	Output Capacitance		V _{OUT} = 2.0 V	f = 1 MHz	8	

Note:

SWITCHING CHARACTERISTICS over COMMERCIAL operating ranges (Note 2)

Parameter Symbol	Parameter Des	ameter Description			Min. (Note 3)	Max.	Unit
tPD	Input or Feedba	ick to Combinatorial Ou	tput	20L8, 20R6, 20R4	1	5	ns
ts	Setup Time from	n Input or Feedback to	Clock		4.5		ns
tн	Hold Time				0		ns
tco	Clock to Output				1	4	ns
tskewr	Skew Between	Registered Outputs (Note 4)				1	ns
tw∟	Clock Width	LOW		20R8, 20R6,	4		ns
twн		HIGH		20R4	4		ns
	Maximum	External Feedback	1/(ts + tco)		117		MHz
fmax	Frequency	Internal Feedback (f	CNT)		125		MHz
	(Note 5)	No Feedback	1/(tw+ + twL)		125		MHz
tezx	OE to Output E	nable			1	6.5	ns
texz	OE to Output D				1	5	ns
tea	Input to Output	Enable Using Product Term Control		20L8, 20R6,	2	6.5	ns
ten	Input to Output	Disable Using Product	Term Control	20R4	2	5	ns

- 2. See Switching Test Circuit for test conditions.
- 3. Output delay minimums are measured under best-case conditions.
- 4. Skew testing takes into account pattern and switching direction differences between outputs that have equal loading.
- 5. These parameters are not 100% tested, but are calculated at initial characterization and at any time the design is modified where the frequency may be affected.

These parameters are not 100% tested, but are evaluated at initial characterization and at any time the design is modified where capacitance may be affected.



Storage Temperature -65°C to +150°C

Ambient Temperature with

Power Applied

-55°C to +125°C

Supply Voltage with

Respect to Ground

-0.5 V to +7.0 V

DC Input Voltage

-1.2 V to Vcc + 0.5 V

DC Output or I/O Pin Voltage Static Discharge Voltage -0.5 V to Vcc + 0.5 V 2001 V

Stresses above those listed under Absolute Maximum Ratings may cause permanent device failure. Functionality at or above these limits is not implied. Exposure to Absolute Maximum.

mum Ratings for extended periods may affect device reliabil-

ity. Programming conditions may differ.

OPERATING RANGES

Commercial (C) Devices

Ambient Temperature (T_A)

Operating in Free Air

Supply Voltage (Vcc)

With Respect to Ground

+4.75 V to +5.25 V

0°C to +75°C

Operating ranges define those limits between which the func-

tionality of the device is guaranteed.

DC CHARACTERISTICS over COMMERCIAL operating ranges unless otherwise specified

Parameter Symbol	Parameter Description	Test Conditions	Min.	Max.	Unit
Vон	Output HIGH Voltage	10H = -3.2 mA VIN = VIH or VIL Vcc = Min.	2.4		V
Vol	Output LOW Voltage	Iol = 24 mA VIN = VIH or VIL VCC = Min.		0.5	V
VIH	Input HIGH Voltage	Guaranteed Input Logical HIGH Voltage for all Inputs (Note 1)	2.0		٧
VIL	Input LOW Voltage	Guaranteed Input Logical LOW Voltage for all Inputs (Note 1)		0.8	٧
Vi	Input Clamp Voltage	I _{IN} = -18 mA, V _{CC} = Min.		-1.2	٧
lін	Input HIGH Current	V _{IN} = 2.7 V, V _{CC} = Max. (Note 2)		25	μA
l _{IL}	Input LOW Current	V _{IN} = 0.4 V, V _{CC} = Max. (Note 2)		-250	μΑ
l)	Maximum Input Current	V _{IN} = 5.5 V, V _{CC} = Max.		_1	mA
lozн	Off-State Output Leakage Current HIGH	V _{OU1} = 2.7 V, V _{CC} = Max. V _{IN} = V _{IH} or V _{IL} (Note 2)		100	μΑ
lozı	Off-State Output Leakage Current LOW	V _{OUT} = 0.4 V, V _{CC} = Max. V _{IN} = V _{IH} or V _{IL} (Note 2)		-100	μΑ
Isc	Output Short-Circuit Current	Vout = 0.5 V, Vcc = Max. (Note 3)	-30	-130	mA
lcc	Supply Current	V _{IN} = 0 V, Outputs Open (lout = 0 mA) V _{CC} = Max.		210	mA

- 1. These are absolute values with respect to device ground and all overshoots due to system and/or tester noise are included.
- 2. I/O pin leakage is the worst case of IIL and IOZL (or IIH and IOZH).
- Not more than one output should be tested at a time. Duration of the short-circuit should not exceed one second. Vout = 0.5 V
 has been chosen to avoid test problems caused by tester ground degradation.

CAPACITANCE (Note 1)

Parameter Symbol	Parameter Description	Test Conditions	s	Тур.	Unit
Cin	Input Capacitance	V _{IN} = 2.0 V	Vcc = 5.0 V	7	
Соит	Output Capacitance	Vout = 2.0 V	$T_A = +25^{\circ}C$ $f = 1 \text{ MHz}$	8	pF

Note:

SWITCHING CHARACTERISTICS over COMMERCIAL operating ranges (Note 2)

Parameter Symbol	Parameter Des	meter Description					Max.	Unit
t _{PD}	Input or Feedba Combinatorial C				20L8, 20R6, 20R4	3	7.5 7	ns
ts	Setup Time fron	n Input or Feed	dback to	Clock		7		ns
tн	Hold Time					0		ns
tco	Clock to Output					3	6.5	ns
tskew	Skew Between	Registered Ou	Registered Outputs (Note 4)				1	ns
twL	Clock Width	LOW	LOW		20R4	5		ns
twн		HIGH			1	5		ns
	Maximum	External Fe	edback	1/(ts + tco)		74		MHz
fmax	Frequency	Internal Fed	edback (icnt)		100		MHz
	(Note 5)	No Feedba	ick	1/(tw+ + twL)	1	100		MHz
tezx	OE to Output Er	nable]	3	8	ns
texz	OE to Output Disable			_	3	8	ns	
tea	Input to Output	utput Enable Using Product Term Control			20L8, 20R6,	3	10	ns
ten	Input to Output	Disable Using	Product	Term Control	20R4	3	10	ns

- 2. See Switching Test Circuit for test conditions.
- 3. Output delay minimums are measured under best-case conditions.
- 4. Skew is measured with all outputs switching in the same direction.
- These parameters are not 100% tested, but are evaluated at initial characterization and at any time the design is modified where the frequency may be affected.

These parameters are not 100% tested, but are evaluated at initial characterization and at any time the design is modified where capacitance may be affected.



Storage Temperature -65°C to +150°C

Ambient Temperature with

Power Applied -55°C to +125°C

Supply Voltage with

Respect to Ground

-0.5 V to +7.0 V

DC Input Voltage

-0.5 V to Vcc + 0.5 V

DC Output or I/O Pin Voltage

-0.5 V to Vcc Max.

DC Input Current

-30 mA to +5 mA

OPERATING RANGES

Commercial (C) Devices

Ambient Temperature (T_A)

Operating in Free Air

0°C to +75°C

Supply Voltage (Vcc)

with Respect to Ground

+4.75 V to +5.25 V

Operating ranges define those limits between which the functionality of the device is guaranteed.

Stresses above those listed under Absolute Maximum Ratings may cause permanent device failure. Functionality at or above these limits is not implied. Exposure to Absolute Maximum Ratings for extended periods may affect device reliability. Programming conditions may differ.

DC CHARACTERISTICS over COMMERCIAL operating ranges unless otherwise specified

Parameter Symbol	Parameter Description	Test Conditions	Min.	Max.	Unit
Vон	Output HIGH Voltage	IOH = -3.2 mA VIN = VIH or VIL VCC = Min.	2.4		>
VOL	Output LOW Voltage	IoL = 24 mA VIN = VIH or VIL Vcc = Min.		0.5	>
ViH	Input HIGH Voltage	Guaranteed Input Logical HIGH Voltage for all Inputs (Note 1)	2.0		٧
ViL	Input LOW Voltage	Guaranteed Input Logical LOW Voltage for all Inputs (Note 1)		0.8	v
Vı	Input Clamp Voltage	I _{IN} = -18 mA, V _{CC} = Min.		-1.5	٧
lін	Input HIGH Current	V _{IN} = 2.7 V, V _{CC} = Max. (Note 2)		25	μА
lı <u>.</u>	Input LOW Current	V _{IN} = 0.4 V, V _{CC} = Max. (Note 2)		-250	μA
h	Maximum Input Current	V _{IN} = 5.5 V, V _{CC} = Max.		100	μΑ
lozн	Off-State Output Leakage Current HIGH	Vout = 2.7 V, Vcc = Max. V _{IN} = V _{IH} or V _{IL} (Note 2)		100	μA
lozı	Off-State Output Leakage Current LOW	Vout = 0.4 V, Vcc = Max. Vin = Vih or Vil (Note 2)		-100	μА
Isc	Output Short-Circuit Current	V _{OUT} = 0.5 V, V _{CC} ≈ Max. (Note 3)	-30	-130	mA
Icc	Supply Current	V _{IN} = 0 V, Outputs Open (lout = 0 mA) V _{CC} = Max.	_	210	mA

- 1. These are absolute values with respect to device ground and all overshoots due to system and/or tester noise are included.
- 2. I/O pin leakage is the worst case of liL and lozL (or liH and lozH).
- Not more than one output should be tested at a time. Duration of the short-circuit should not exceed one second. Vout = 0.5 V
 has been chosen to avoid test problems caused by tester ground degradation.

CAPACITANCE (Note 1)

Parameter Symbol	Parameter Description	Test Conditio	ns		Тур.	Unit
Cin	Input Capacitance	Vin = 2.0 V	Vcc = 5.0 V	CLK, ÖE	12	
1	•		T _A = 25°C	Other Inputs	7	pF
Соит	Output Capacitance	Vout = 2.0 V	f = 1 MHz	Outputs	8	

Note:

SWITCHING CHARACTERISTICS over COMMERCIAL operating ranges (Note 2)

Parameter Symbol	Parameter Description				Min. (Note 3)	Max.	Unit
tpo	Input or Feedba Combinatorial (20L8, 20R6, 20R4	3	10	ns
ts	Setup Time from	m Input or Feedback to	Clock		10		ns
tн	Hold Time				0		ns
tco	Clock to Output	t		20R8, 20R6,	2	8	ns
twL	Clock Width	LOW		20R4	7		ns
twн		HIGH			7		ns
	Maximum	External Feedback	1/(ts + tco)		55.5		MHz
fmax	Frequency	Internal Feedback (fcnt)			58.8		MHz
	(Note 5)	No Feedback	1/(tw+ + twL)		71.4		MHz
tpzx	OE to Output E	nable			1	10	ns
texz	OE to Output Disable				1	10	ns
1EA	Input to Output Enable Using Product Term Control			20L8, 20R6,	3	10	ns
ten	Input to Output	Disable Using Product	Term Control	20R4	3	10	ns

- 2. See Switching Test Circuit for test conditions.
- 3. Output delay minimums are measured under best-case conditions.
- 4. Calculated from measured fMAX internal.
- These parameters are not 100% tested, but are calculated at initial characterization and at any time the design is modified where the frequency may be affected.

These parameters are not 100% tested, but are evaluated at initial characterization and at any time the design is modified where capacitance may be affected.



Storage Temperature --65°C to +150°C

Ambient Temperature with

ity. Programming conditions may differ.

Power Applied -55°C to +125°C

Supply Voltage with

Respect to Ground -0.5 V to +7.0 V

DC Input Voltage -1.5 V to Vcc + 0.5 V

DC Output or I/O Pin Voltage -0.5 V to Vcc + 0.5 V

Stresses above those listed under Absolute Maximum Ratings may cause permanent device failure. Functionality at or above these limits is not implied. Exposure to Absolute Maximum Ratings for extended periods may affect device reliabil-

OPERATING RANGES

Commercial (C) Devices

Ambient Temperature (T_A)

Operating in Free Air 0°C to +75°C

Supply Voltage (Vcc)

with Respect to Ground

+4.75 V to +5.25 V

Operating ranges define those limits between which the functionality of the device is guaranteed.

DC CHARACTERISTICS over COMMERCIAL operating ranges unless otherwise specified

Parameter Symbol	Parameter Description	Test Conditions	Min.	Max.	Unit
Vон	Output HIGH Voltage	IOH = -3.2 mA VIN = VIH or VIL Vcc = Min.	2.4		٧
Vol	Output LOW Voltage	lot = 24 mA VIN = VIH or VIL Vcc = Min.		0.5	V
VIH	Input HIGH Voltage	Guaranteed Input Logical HIGH Voltage for all Inputs (Note 1)			٧
VIL	Input LOW Voltage	Guaranteed Input Logical LOW Voltage for all Inputs (Note 1)		0.8	٧
Vı	Input Clamp Voltage	I _{IN} = -18 mA, Vcc = Min.		-1.5	٧
lн	Input HIGH Current	V _{IN} = 2.7 V, V _{CC} = Max. (Note 2)		25	μА
lı.	Input LOW Current	V _{IN} = 0.4 V, V _{CC} = Max. (Note 2)		-250	μΑ
l ₁	Maximum Input Current	V _{IN} = 5.5 V, V _{CC} = Max.		100	μА
lozн	Off-State Output Leakage Current HIGH	Vout = 2.7 V, Vcc = Max. Vin = Vihor Vit (Note 2)		100	μА
lozı	Off-State Output Leakage Current LOW	Vout = 0.4 V, Vcc = Max. Vin = Vih or Vil (Note 2)		-100	μА
Isc	Output Short-Circuit Current	Vout = 0.5 V, Vcc = Max. (Note 3)	-30	-130	mA
lcc	Supply Current	V _{IN} = 0 V, Outputs Open (lout = 0 mA) V _{CC} = Max.		210	mA

- 1. These are absolute values with respect to device ground and all overshoots due to system and/or tester noise are included.
- 2. I/O pin leakage is the worst case of IIL and lozL (or IIH and lozH).
- 3. Not more than one output should be tested at a time. Duration of the short-circuit should not exceed one second. V_{OUT} = 0.5 V has been chosen to avoid test problems caused by tester ground degradation.



SWITCHING CHARACTERISTICS over COMMERCIAL operating ranges (Note 1)

Parameter Symbol	Parameter Des	Parameter Description					Unit
tPD	Input or Feedba Combinatorial (15	ns
ts	Setup Time from	m Input or Feedback to		15		ns	
tн	Hold Time	-		0		ns	
tco	Clock to Output	or Feedback		20R8, 20R6,		12	ns
twL	Clock Width	LOW		20R4	10		ns
twн		HIGH			12		ns
fmax	Maximum Frequency	External Feedback	1/(ts + tco)		37		MHz
IMAA	(Note 2)	No Feedback	1/(tw+ + twL)		45		MHz
tezx	OE to Output E	nable				15	ns
t _P xz	OE to Output Disable				12	ns	
t <u>e</u> a	Input to Output	Input to Output Enable Using Product Term Control		20L8, 20R6,		18	ns
ter	Input to Output	Disable Using Product	Term Control	20R4		15	ns

^{1.} See Switching Test Circuit for test conditions.

These parameters are not 100% tested, but are calculated at initial characterization and at any time the design is modified where frequency may be affected.



Storage Temperature

-65°C to +150°C

Ambient Temperature with

Power Applied -55°C to +125°C

Supply Voltage with

Respect to Ground

-0.5 V to +7.0 V

-1.5 V to Vcc + 0.5 V DC Input Voltage

DC Output or I/O Pin Voltage

-0.5 V to Vcc + 0.5 V

OPERATING RANGES

Ambient Temperature (T_A)

Commercial (C) Devices

Operating in Free Air

Supply Voltage (Vcc)

with Respect to Ground

tionality of the device is guaranteed.

+4.75 V to +5.25 V

0°C to +75°C

Operating ranges define those limits between which the func-

Stresses above those listed under Absolute Maximum Ratings may cause permanent device failure. Functionality at or above these limits is not implied. Exposure to Absolute Maximum Ratings for extended periods may affect device reliability. Programming conditions may differ.

DC CHARACTERISTICS over COMMERCIAL operating ranges unless otherwise specified

Parameter Symbol	Parameter Description	Test Conditions	Min.	Max.	Unit
Vон	Output HIGH Voltage	loн = −3.2 mA Vın = Vıн or Vı∟ Vcc = Min.	2.4		٧
Vol	Output LOW Voltage	IoL = 24 mA V _{IN} = V _{IH} or V _{IL} V _{CC} ≠ Min.		0.5	٧
ViH	Input HIGH Voltage	Guaranteed Input Logical HIGH Voltage for all Inputs (Note 1)			٧
VIL	Input LOW Voltage	Guaranteed Input Logical LOW Voltage for all Inputs (Note 1)		0.8	٧
Vı	Input Clamp Voltage	In = -18 mA, Vcc = Min.		-1.5	٧
Ін	Input HIGH Current	V _{IN} = 2.7 V, V _{CC} = Max. (Note 2)		25	μΑ
lıL .	Input LOW Current	V _{IN} = 0.4 V, V _{CC} = Max. (Note 2)		-250	μА
lı	Maximum Input Current	Vin = 5.5 V, Vcc = Max.		100	μA
lozн	Off-State Output Leakage Current HIGH	Vout = 2.7 V, Vcc = Max. Vin = ViHor ViL (Note 2)		100	μА
lozı	Off-State Output Leakage Current LOW	Vout = 0.4 V, Vcc = Max. Vin = ViHor ViL (Note 2)		-100	μА
Isc	Output Short-Circuit Current	Vouт = 0.5 V, Vcc = Max. (Note 3)	-30	-130	mA
lcc	Supply Current	V _{IN} = 0 V, Outputs Open (lout = 0 mA) Vcc = Max.		105	mA

- 1. These are absolute values with respect to device ground and all overshoots due to system and/or tester noise are included.
- 2. I/O pin leakage is the worst case of IIL and IOZL (or IIH and IOZH).
- 3. Not more than one output should be tested at a time. Duration of the short-circuit should not exceed one second. Vour = 0.5 V has been chosen to avoid test problems caused by tester ground degradation.



SWITCHING CHARACTERISTICS over COMMERCIAL operating ranges (Note 1)

Parameter Symbol	Parameter Des	Parameter Description					Unit
tPD		ck to Combinatorial Output		20L8, 20R6, 20R4		25	ns
ts	Setup Time from	Setup Time from Input or Feedback to Clock			25		ns
tн	Hold Time			0		ns	
tco	Clock to Output			20R8, 20R6,		15	ns
twL	Clock Width	LOW		20R4	15		ns
twн		HIGH			15		ns
	Maximum	External Feedback	1/(ts_+ tco)		25		MHz
fmax	Frequency	Internal Feedback (f	CNT)		28.5		MHz
	(Note 3)	No Feedback	1/(tw+ + twL)		33.3		MHz
tpzx	ŌE to Output Er	nable	•			20	ns
texz	OE to Output Di	DE to Output Disable				20	ns
tea .	Input to Output	Enable Using Product 1	20L8, 20R6,		25	ns	
ter	Input to Output	Disable Using Product	Term Control	20R4		25	ns

- 1. See Switching Test Circuit for test conditions.
- 2. Calculated from measured fMAX internal.
- These parameters are not 100% tested, but are calculated at initial characterization and at any time the design is modified where frequency may be affected.



Storage Temperature

-65°C to +150°C

Ambient Temperature with

Power Applied

-55°C to +125°C

Supply Voltage with

Respect to Ground

-0.5 V to +7.0 V

DC input Voltage

-1.5 V to Vcc + 0.5 V

DC Output or I/O Pin Voltage

-0.5 V to Vcc + 0.5 V

OPERATING RANGES

Commercial (C) Devices

Ambient Temperature (TA)

Operating in Free Air

0°C to +75°C

Supply Voltage (Vcc)

with Respect to Ground

+4.75 V to +5.25 V

Operating ranges define those limits between which the func-

tionality of the device is guaranteed.

Stresses above those listed under Absolute Maximum Ratings may cause permanent device failure. Functionality at or above these limits is not implied. Exposure to Absolute Maximum Ratings for extended periods may affect device reliability. Programming conditions may differ.

DC CHARACTERISTICS over COMMERCIAL operating ranges unless otherwise specified

Parameter Symbol	Parameter Description	Test Conditions	Min.	Max.	Unit
Vон	Output HIGH Voltage	IOH = -3.2 mA VIN = VIH or VIL Vcc = Min.	2.4		٧
VoL	Output LOW Voltage	IoL = 24 mA VIN = VIH or VIL Vcc = Min.		0.5	٧
ViH	Input HIGH Voltage	Guaranteed Input Logical HiGH Voltage for all Inputs (Note 1)			٧
VIL	Input LOW Voltage	Guaranteed Input Logical LOW Voltage for all Inputs (Note 1)		0.8	V
Vı	Input Clamp Voltage	In = -18 mA, Vcc = Min.		-1.5	٧
lin	Input HIGH Current	V _{IN} = 2.7 V, V _{CC} = Max. (Note 2)		25	μА
lı.	Input LOW Current	V _{IN} = 0.4 V, V _{CC} = Max. (Note 2)		-250	μА
lı	Maximum Input Current	VIN = 5.5 V, Vcc = Max.		100	μA
lozн	Off-State Output Leakage Current HIGH	Vout = 2.7 V, Vcc = Max. Vin = Vih or ViL (Note 2)	_	100	μА
lozı.	Off-State Output Leakage Current LOW	Vout = 0.4 V, Vcc = Max. Vin = Vin or Vil (Note 2)		-100	μА
Isc	Output Short-Circuit Current	Vout = 0.5 V, Vcc = Max. (Note 3)	-30	-130	mA
lcc	Supply Current	V _{IN} = 0 V, Outputs Open (lout = 0 mA) Vcc = Max.		210	mA

- 1. These are absolute values with respect to device ground and all overshoots due to system and/or tester noise are included.
- 2. I/O pin leakage is the worst case of lil and lozi, (or lin and lozi).
- 3. Not more than one output should be tested at a time. Duration of the short-circuit should not exceed one second. VOUT = 0.5 V has been chosen to avoid test problems caused by tester ground degradation.



SWITCHING CHARACTERISTICS over COMMERCIAL operating ranges (Note 1)

Parameter Symbol	Parameter Des	scription	Min.	Max.	Unit		
t _{PD}	Input or Feedba	ack to Combinatorial Ou	k to Combinatorial Output			25	ns
ts	Setup Time fro	m Input or Feedback to		25		ns	
tн	Hold Time						ns
tco	Clock to Outpu			20R8, 20R6,		15	ns
tw∟	Clock Width	LOW		20R4	15	1	ns
twн		HIGH			15	_	ns
	Maximum	External Feedback	1/(ts + tco)		25		MHz
f MAX	Frequency	Internal Feedback (f	CNT)		28.5		MHz
	(Note 3)	No Feedback	1/(twn + twl)		33		MHz
tezx	OE to Output E	nable				20	ns
texz	OE to Output Disable					20	ns
tea	Input to Output Enable Using Product Term Control			20L8, 20R6,		25	ns
ter	Input to Output	Disable Using Product	Term Control	20R4	·	25	ns

- 1. See Switching Test Circuit for test conditions.
- 2. Calculated from measured fmax internal.
- 3. These parameters are not 100% tested, but are calculated at initial characterization and at any time the design is modified where frequency may be affected.



Storage Temperature -65°C to +150°C

Ambient Temperature

With Power Applied -55°C to +125°C

Supply Voltage with

Respect to Ground -0.5 V to +7.0 V

DC Input Voltage -1.2 V to Vcc + 0.5 V

DC Output or I/O Pin Voltage -0.5 V to Vcc + 0.5 V Static Discharge Voltage 2001 V

Stresses above those listed under Absolute Maximum Ratings may cause permanent device failure. Functionality at or above these limits is not implied. Exposure to Absolute Maximum Ratings for extended periods may affect device reliability. Programming conditions may differ. Absolute Maximum Ratings are for system design reference; parameters given are not tested.

OPERATING RANGES

Military (M) Devices (Note 1)

Operating Case (Tc)

Temperature -55°C to +125°C

Supply Voltage (Vcc)

With Respect to Ground

+4.50 V to +5.50 V

Operating ranges define those limits between which the functionality of the device is guaranteed.

Note:

1. Military products are 100% tested at Tc = +25 °C , +125 °C, and -55°C.

DC CHARACTERISTICS over MILITARY operating ranges unless otherwise specified (Note 2)

Parameter Symbol	Parameter Description	Test Conditions	Min.	Max.	Unit
Vон	Output HIGH Voltage	IOH = -2 mA VIN = VIH Or VIL VCC = Min	2.4		٧
Vol	Output LOW Voltage	IoL = 12 mA VIN = VIH or VIL Vcc = Min		0.5	٧
ViH	Input HIGH Voltage	Guaranteed Input Logical HIGH Voltage for all Inputs (Note 3)	2.0		>
VIL	Input LOW Voltage	Guaranteed Input Logical LOW Voltage for all Inputs (Note 3)		0.8	٧
Vı	Input Clamp Voltage	I _{IN} = -18 mA, V _{CC} = Min		-1.2	٧
liн .	Input HIGH Current	V _{IN} = 2.4 V, V _{CC} = Max. (Note 4)		25	μА
lit.	Input LOW Current	V _{IN} = 0.4 V, V _{CC} = Max. (Note 4)		-250	μΑ
lı	Maximum Input Current	V _{IN} = 5.5 V, V _{CC} = Max.		1	mA
Іогн	Off-State Output Leakage Current HIGH	Vout = 2.4 V, Vcc = Max. Vin = Vih or ViL (Note 4)		100	μА
lozı	Off-State Output Leakage Current LOW	Vout = 0.4 V, Vcc = Max. Vin = Vih or Vil (Note 4)		-100	μА
Isc	Output Short-Circuit Current	Vout = 0.5 V, Vcc = Max. (Note 5)	-30	-130	mA
lcc	Supply Current	Vin = 0 V, Outputs Open (lout = 0 mA) Vcc = Max.		210	mA

- 2. For APL Products, Group A, Subgroups 1, 2, and 3 are tested per MIL-STD-883, Method 5005, unless otherwise noted.
- 3. VIL and VIH are input conditions of output tests and are not themselves directly tested. VIL and VIH are absolute voltages with respect to device ground and include all overshoots due to system and/or tester noise. Do not attempt to test these values without suitable equipment.
- 4. I/O pin leakage is the worst case of IIL and IOZL (or IIH and IOZH).
- 5. Not more than one output should be tested at a time. Duration of the short-circuit should not exceed one second. Vout = 0.5 V has been chosen to avoid test problems caused by tester ground degradation.

CAPACITANCE (Note 1)

Parameter Symbol	Parameter Descriptions	Test Conditions		Тур.	Unit
Cin	Input Capacitance	VIN = 2.0 V	Vcc = 5.0 V	9	_
Соит	Output Capacitance	Vout = 2.0 V	T _A = +25°C f = 1 MHz	10	pF

Note:

SWITCHING CHARACTERISTICS over MILITARY operating ranges (Note 2)

	<u> </u>								
•		-			-10	-10			
Parameter Symbol	Parameter Des	cription			Min. (Note 3)	Max.	Min. (Note 3)	Max.	Unit
tPD	Input or Feedback to Combinatorial Output			20L8, 20R6, 20R4	3	10	3	12	ns
ts	Setup Time from	n Input or Feedback to	Clock		10		12		ns
tн	Hold Time				0		0		ns
tco	Clock to Output					10	3	12	ns
tskew	Skew Between I	Registered Outputs (N	Note 4)			1		1	ns
twL	Clock Width	LOW		20R8,	8		10		ns
twн		HIGH		20R6, 20R4	8		10		ns
fmax	Maximum	External Feedback	1/(ts + tco)		50		41.7		MHz
	Frequency	Internal Feedback	(fcnt)		62.5		50		MHz
	(Note 5)	No Feedback	1/(twH + twL)		62.5		50		MHz
tezx	OE to Output Er	nable (Note 5)			3	12	3	15	ns
texz	OE to Output Disable (Note 5)				3	12	3	15	ns
tea	Input to Output Enable Using Product Term Control (Note 5)		20L8,	3	12	3	15	ns	
tea	Input to Output I Term Control (N	Disable Using Production (1975)	t	20R6, 20R4	3	12	3	15	ns

- See Switching Test Circuit for test conditions. For APL products Group A, Subgroups 9, 10, and 11 are tested per MIL-STD-883, Method 5005, unless otherwise noted.
- Minimum value for tpp, tco, tpzx, tpxz, tea, and ten parameters should be used for simulation purposes only and are not tested.
- 4. Skew is measured with all outputs switching in the same direction.
- These parameters are not 100% tested, but are evaluated at initial characterization and at any time the design is modified where these parameters may be affected.

These parameters are not 100% tested, but are evaluated at initial characterization and at any time the design is modified where capacitance may be affected.



Storage Temperature -65°C to +150°C

Ambient Temperature

with Power Applied -55°C to +125°C

Supply Voltage with

DC Input Current

Respect to Ground

-0.5 V to +7.0 V

DC Input Voltage -0.5 V to +5.5 V

DC Output or I/O Pin Voltage

-0.5 V to Vcc Max.

Stresses above those listed under Absolute Maximum Ratings may cause permanent device failure. Functionality at or above these limits is not implied. Exposure to Absolute Maximum Ratings for extended periods may affect device reliability. Programming conditions may differ. Absolute Maximum Ratings are for system design reference; parameters given are not tested.

OPERATING RANGES

Military (M) Devices (Note 1)

Ambient Temperature (T_A)

Operating in Free Air

-55°C Min.

Operating Case (Tc)

Temperature

+125°C Max.

Supply Voltage (Vcc)

with Respect to Ground

+4.50 V to +5.50 V

Operating ranges define those limits between which the functionality of the device is guaranteed.

Note:

 Military products are tested at T_C = +25°C, +125°C, and -55°C per MiL-STD-883.

DC CHARACTERISTICS over MILITARY operating ranges unless otherwise specified (Note 2)

Parameter Symbol	Parameter Description	Test Conditions	Min.	Max.	Unit
Vон	Output HIGH Voltage	IOH = -2 mA V _{IN} = V _{IH} or V _{IL} Vcc = Min.	2.4		٧
Vol	Output LOW Voltage	lot = 12 mA V _{IN} = V _{IH} or V _{IL} Vcc = Min.		0.5	٧
ViH	Input HIGH Voltage	Guaranteed Input Logical HIGH Voltage for all Inputs (Note 3)	2.0		٧
VIL	Input LOW Voltage	Guaranteed Input Logical LOW Voltage for all Inputs (Note 3)		0.8	٧
Vı	Input Clamp Voltage	I _{IN} = -18 mA, V _{CC} = Min.		-1.5	٧
lн	Input HIGH Current	V _{IN} = 2.4 V, V _{CC} = Max. (Note 4)		25	μА
l _{IL}	Input LOW Current	V _{IN} = 0.4 V, V _{CC} = Max. (Note 4)		-250	μА
li	Maximum Input Current	V _{IN} = 5.5 V, V _{CC} = Max.		100	μA
lozн	Off-State Output Leakage Current HIGH	Vout = 2.7 V, Vcc = Max. Vin = Vinor Vil (Note 4)		100	μA
lozı	Off-State Output Leakage Current LOW	Vout = 0.4 V, Vcc = Max. Vin = Vihor Vil. (Note 4)		-100	μА
Isc	Output Short-Circuit Current	Vout = 0.5 V, Vcc = Max. (Note 5)	-30	-130	mA
lcc	Supply Current	Vin = 0 V, Outputs Open (lout = 0 mA) Vcc = Max.		210	mA

- 2. For APL Products, Group A, Subgroups 1, 2, and 3 are tested per MIL-STD-883, Method 5005, unless otherwise noted.
- VIL and VIH are input conditions of output tests and are not themselves directly tested. VIL and VIH are absolute voltages with
 respect to device ground and include all overshoots due to system and/or tester noise. Do not attempt to test these values
 without suitable equipment.
- 4. I/O pin leakage is the worst case of IIL and IOZL (or IIH and IOZH).
- Not more than one output should be tested at a time. Duration of the short-circuit should not exceed one second. Vout = 0.5 V
 has been chosen to avoid test problems caused by tester ground degradation.

CAPACITANCE (Note 1)

Parameter Symbol	Parameter Description	Test Conditio	ns		Тур.	Unit
Cin	Input Capacitance	VIN = 2.0 V	Vcc = 5.0 V	CLK, OE	12	
			TA = 25°C	Other Inputs	7	pF
Соит	Output Capacitance	Vout = 2.0 V	f = 1 MHz	Outputs	8	

Note:

SWITCHING CHARACTERISTICS over MILITARY operating ranges (Note 2)

Parameter Symbol	Parameter Des	scription			Min. (Note 3)	Max.	Unit
tpd	Input or Feedba Combinatorial (20L8, 20R6, 20R4	3	15	ns
ts	Setup Time from	m Input or Feedback to	Clock	<u></u> -	15		ns
tн	Hold Time				0		ns
tco	Clock to Output	ţ		2	13	ns	
twL	Clock Width	LOW		20R8, 20R6,	10		ns
twн		HIGH		20R4	10		ns
	Maximum	External Feedback	1/(ts + tco)		35.7		MHz
fmax	Frequency	Internal Feedback (fcnt)			37		MHz
	(Note 5)	No Feedback	1/(tw+ + twL)	li	50		MHz
tezx	OE to Output E	nable (Note 6)			1	15	ns
texz	OE to Output D	isable (Note 6)			1	15	ns
tea		t to Output Enable Using Product n Control (Note 6)			3	15	ns
ten	Input to Output Term Control (I	Disable Using Product Note 6)		20L8, 20R6, 20R4	3	15	ns

- See Switching Test Circuit for test conditions. For APL products Group A, Subgroups 9, 10, and 11 are tested per MIL-STD-883, Method 5005, unless otherwise noted.
- Minimum value for tpD, tco, tpzx, tpxz, teA, and teR parameters should be used for simulation purposes only and are not tested.
- 4. Calculated from measured fMAX internal.
- These parameters are not 100% tested, but are calculated at initial characterization and at any time the design is modified where frequency may be affected.
- These parameters are not 100% tested, but are evaluated at initial characterization and at any time the design is modified where these parameters may be affected.

These parameters are not 100% tested, but are evaluated at initial characterization and at any time the design is modified where capacitance may be affected.



-65°C to +150°C Storage Temperature

Ambient Temperature

with Power Applied

-55°C to +125°C

Supply Voltage with

Respect to Ground -0.5 V to +7.0 V

-1.5 V to + 5.5 V DC Input Voltage

DC Output or I/O Pin Voltage

Temperature +125°C Max. Supply Voltage (Vcc)

OPERATING RANGES

Operating in Free Air

Operating Case (Tc)

Military (M) Devices (Note 1)

Ambient Temperature (T_A)

+4.50 V to +5.50 V with Respect to Ground

-55°C Min.

Stresses above those listed under Absolute Maximum Ratings may cause permanent device failure. Functionality at or above these limits is not implied. Exposure to Absolute Maximum Ratings for extended periods may affect device reliability. Programming conditions may differ. Absolute Maximum Ratings are for system design reference; parameters given are not tested.

Operating ranges define those limits between which the functionality of the device is guaranteed.

Note:

1. Military products are tested at Tc = +25°C, +125°C, and -55°C per MIL-STD-883.

DC CHARACTERISTICS over MILITARY operating ranges unless otherwise specified (Note 2)

5.5 V

Parameter Symbol	Parameter Description	Test Conditions	Min.	Max.	Unit
Vон	Output HIGH Voltage	IOH = -2 mA VIN = VIH or VIL Vcc = Min.	2.4		٧
Vol	Output LOW Voltage	IoL = 12 mA VIN = VIH or VIL Vcc = Min.		0.5	٧
Viн	Input HIGH Voltage	Guaranteed Input Logical HIGH Voltage for all Inputs (Note 3)	2.0		٧
VIL	Input LOW Voltage	Guaranteed Input Logical LOW Voltage for all Inputs (Note 3)		0.8	٧
Vı	Input Clamp Voltage	l _{IN} = −18 mA, Vcc = Min.		-1.5	٧
lин	Input HIGH Current	V _{IN} = 2.4 V, V _{CC} = Max. (Note 4)		25	μА
1 _{IL}	Input LOW Current	V _{IN} = 0.4 V, V _{CC} = Max. (Note 4)		-250	μΑ
lı	Maximum Input Current	V _{IN} = 5.5 V, V _{CC} = Max.		1	mA
lozн	Off-State Output Leakage Current HIGH	Vout = 2.4 V, Vcc = Max. Vin = Vih or Vil. (Note 4)		100	μА
loziL	Off-State Output Leakage Current LOW	Vout = 0.4 V, Vcc = Max. Vin = Vih or ViL (Note 4)		-100	μА
Isc	Output Short-Circuit Current	Vout = 0.5 V, Vcc = Max. (Note 5)	-30	-130	mA
Icc	Supply Current	V _{IN} = 0 V, Outputs Open (lout = 0 mA) Vcc = Max.		210	mA

- 2. For APL Products, Group A, Subgroups 1, 2, and 3 are tested per MIL-STD-883, Method 5005, unless otherwise noted.
- 3. Vit and ViH are input conditions of output tests and are not themselves directly tested. Vit and ViH are absolute voltages with respect to device ground and include all overshoots due to system and/or tester noise. Do not attempt to test these values without suitable equipment.
- 4. VO pin leakage is the worst case of IIL and lozL (or IIH and lozH).
- 5. Not more than one output should be tested at a time. Duration of the short-circuit should not exceed one second. Vour = 0.5 V has been chosen to avoid test problems caused by tester ground degradation.



SWITCHING CHARACTERISTICS over MILITARY operating ranges (Note 1)

Parameter Symbol	Parameter Description					Max.	Unit
t _{PD}	Input or Feedba	ack to Combinatorial Ou	itput	20L8, 20R6, 20R4		20	ns
ts	Setup Time from	m Input or Feedback to	Clock		20		ns
tн	Hold Time			0		ns	
tco	Clock to Output	or Feedback				15	ns
twL		LOW		20R8, 20R6,	12		ns
twн	Clock Width	HIGH			12		ns
fmax	Maximum	External Feedback	1/(ts + tco)		28.5		MHz
	Frequency (Note 2)	No Feedback	1/(tw+ + twL)		41.6		MHz
tpzx	OE to Output E	nable (Note 3)				20	ns
texz	OE to Output D	isable (Note 3)				20	ns
1EA	Input to Output Term Control (I	Enable Using Product Note 3)	20L8, 20R6,		25	ns	
ten	Input to Output Term Control (I	Disable Using Product Note 3)				20	ns

- See Switching Test Circuit for test conditions. For APL products Group A, Subgroups 9, 10, and 11 are tested per MIL-STD-883, Method 5005, unless otherwise noted.
- 2. These parameters are not 100% tested, but are calculated at initial characterization and at any time the design is modified where frequency may be affected.
- 3. These parameters are not 100% tested, but are evaluated at initial characterization and at any time the design is modified where these parameters may be affected.



Storage Temperature -65°C to +150°C

Ambient Temperature

with Power Applied -55

-55°C to +125°C

Supply Voltage with

are not tested.

Respect to Ground -0.5 V to +7.0 V

DC Input Voltage -1.5 V to +5.5 V

DC Output or I/O Pin Voltage 5.5 V

Stresses above those listed under Absolute Maximum Ratings may cause permanent device failure. Functionality at or above these limits is not implied. Exposure to Absolute Maximum Ratings for extended periods may affect device reliability. Programming conditions may differ. Absolute Maximum Ratings are for system design reference; parameters given

OPERATING RANGES

Military (M) Devices (Note 1)

Ambient Temperature (T_A)

Operating in Free Air -55°C Min.

Operating Case (Tc)

Temperature

+125°C Max.

Supply Voltage (Vcc)

with Respect to Ground

+4.50 V to +5.50 V

Operating ranges define those limits between which the functionality of the device is guaranteed.

Note:

 Military products are tested at T_C = +25°C, +125°C, and -55°C per MIL-STD-883.

DC CHARACTERISTICS over MILITARY operating ranges unless otherwise specified (Note 2)

Parameter Symbol	Parameter Description	Test Conditions	Min.	Max.	Unit
Vон	Output HIGH Voltage	IOH = -2 mA VIN = VIH or VIL Vcc = Min.	2.4		V
Vol	Output LOW Voltage	IoL = 12 mA V _{IN} = V _{IH} or V _{IL} V _{CC} = Min.		0.5	٧
ViH	Input HIGH Voltage	Guaranteed Input Logical HIGH Voltage for all Inputs (Note 3)	2.0		٧
Vil.	Input LOW Voltage	Guaranteed Input Logical LOW Voltage for all Inputs (Note 3)	_	0.8	٧
Vı	Input Clamp Voltage	I _{IN} = -18 mA, V _{CC} = Min.		-1.5	٧
lan .	Input HIGH Current	Vin = 2.4 V, Vcc = Max. (Note 4)		25	μА
IIL	Input LOW Current	V _{IN} = 0.4 V, V _{CC} = Max. (Note 4)		-250	μΑ
li	Maximum Input Current	V _{IN} = 5.5 V, V _{CC} = Max.		1	mA
Юżн	Off-State Output Leakage Current HIGH	Vout = 2.4 V, Vcc = Max. Vin = Vih or Vil. (Note 4)		100	μА
lozı	Off-State Output Leakage Current LOW	Vout = 0.4 V, Vcc = Max. Vin = Vihor Vil. (Note 4)		-100	μА
Isc	Output Short-Circuit Current	Vоит = 0.5 V, Vcc = Max. (Note 5)	-30	-130	mA
lcc	Supply Current	Vin = 0 V, Outputs Open (lour = 0 mA) Vcc = Max.		210	mA

- 2. For APL Products, Group A, Subgroups 1, 2, and 3 are tested per MIL-STD-883, Method 5005, unless otherwise noted.
- VIL and VIH are input conditions of output tests and are not themselves directly tested. VIL and VIH are absolute voltages with
 respect to device ground and include all overshoots due to system and/or tester noise. Do not attempt to test these values
 without suitable equipment.
- 4. I/O pin leakage is the worst case of IIL and IOZL (or IIH and IOZH).
- Not more than one output should be tested at a time. Duration of the short-circuit should not exceed one second. Vour = 0.5 V
 has been chosen to avoid test problems caused by tester ground degradation.

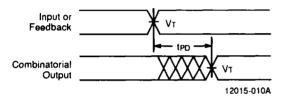


SWITCHING CHARACTERISTICS over MILITARY operating ranges (Note 1)

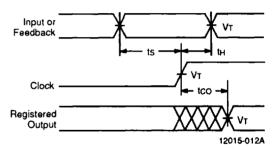
Parameter Symbol	Parameter Des	rarameter Description					Unit
tPD	Input or Feedba	ack to Combinatorial Ou	itput	20L8, 20R6, 20R4		30	ns
ts	Setup Time from	m Input or Feedback to	Clock		30		ns
t _H	Hold Time				0		ns
tco	Clock to Output	t or Feedback	or Feedback			20	ns
tw∟	Clock Width	LOW	LOW		20		ns
twn		HIGH	HIGH		20		ns
	Maximum	External Feedback	1/(ts + tco)		20		MHz
fmax	Frequency (Note_2)	No Feedback	1/(tw+ + twL)		25		MHz
tpzx	OE to Output E	nable (Note 3)				25	ns
texz	OE to Output D	isable (Note 3)				25	ns
1 EA		nput to Output Enable Using Product erm Control (Note 3)				30	ns
ter	Input to Output Term Control (I	Disable Using Product Note 3)		20R4		30	ns

- See Switching Test Circuit for test conditions. For APL products Group A, Subgroups 9, 10, and 11 are tested per MIL-STD-883, Method 5005, unless otherwise noted.
- 2. These parameters are not 100% tested, but are calculated at initial characterization and at any time the design is modified where frequency may be affected.
- These parameters are not 100% tested, but are evaluated at initial characterization and at any time the design is modified where these parameters may be affected.

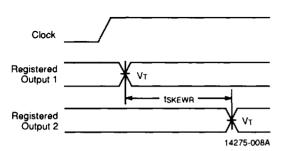
SWITCHING WAVEFORMS



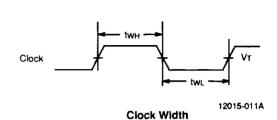
Combinatorial Output

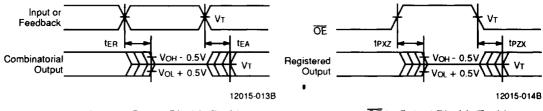


Registered Output



Registered Output Skew



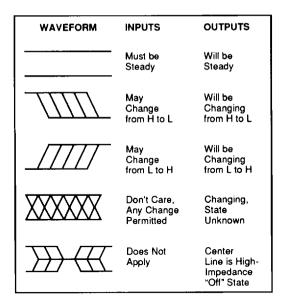


Input to Output Disable/Enable

OE to Output Disable/Enable

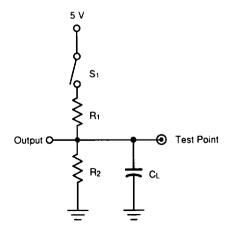
- 1. VT = 1.5 V
- Input pulse amplitude 0 V to 3.0 V
 Input rise and fall times 2-3 ns typical.

KEY TO SWITCHING WAVEFORMS



KS000010-PAL

SWITCHING TEST CIRCUIT

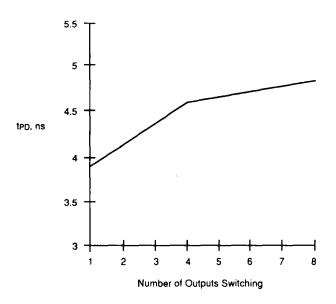


12350-019A

			Comm	nercial	Measured
Specification	S ₁	CL	R ₁	R₂	Output Value
tpp, tco	Closed				1.5 V
tpzx, tea	Z → H: Open Z → L: Closed	50 pF	200 Ω	200 Ω	1.5 V
texz, ten	H → Z: Open L → Z: Closed	5 pF	_		H → Z: VoH − 0.5 V L → Z: VoL + 0.5 V

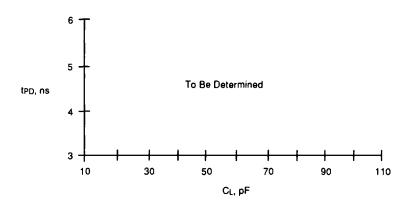
MEASURED SWITCHING CHARACTERISTICS FOR THE PAL20R8-5

Vcc = 4.75 V, Ta = 75°C (Note 1)



tpp vs. Number of Outputs Switching

10294-005B



ted vs. Load Capacitance

10294-006A

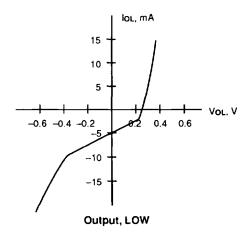
Note:

 These parameters are not 100% tested, but are evaluated at initial characterization and at any time the design is modified where tpp may be affected.

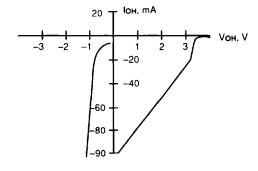


CURRENT VS. VOLTAGE (I-V) CHARACTERISTICS FOR THE PAL20R8-5

Vcc = 5.0 V, $T_A = 25$ °C

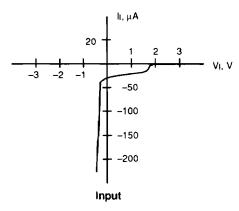


10240-003B



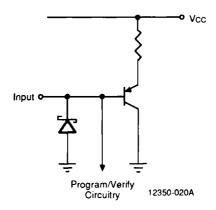
Output, HIGH

10240-004B

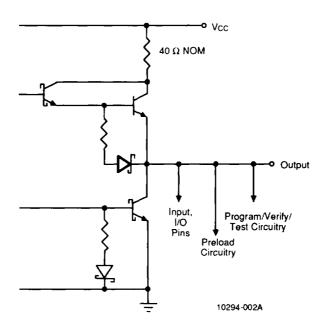


10240-005A

INPUT/OUTPUT EQUIVALENT SCHEMATICS



Typical Input



Typical Output

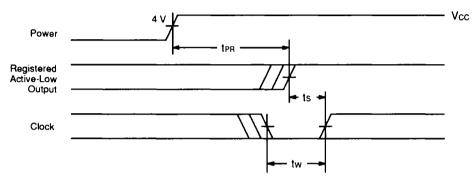
POWER-UP RESET

The power-up reset feature ensures that all flip-flops will be reset to LOW after the device has been powered up. The output state will be HIGH due to the inverting output buffer. This feature is valuable in simplifying state machine initialization. A timing diagram and parameter table are shown below. Due to the synchronous operation of the power-up reset and the wide range of ways Vcc

can rise to its steady state, two conditions are required to ensure a valid power-up reset. These conditions are:

- 1. The Vcc rise must be monotonic.
- Following reset, the clock input must not be driven from LOW to HIGH until all applicable input and feedback setup times are met.

Parameter Symbol	Parameter Description	Max.	Unit		
tpp	Power-up Reset Time	1000	ns		
ts	Input or Feedback Setup Time	See Switch	hing		
tw∟	Clock Width LOW	Characteri	Characteristics		



12350-024A

Power-Up Reset Waveform